

## Power Hall IC with Complementary Output

### ◆ General Description

The YH279 is an integrated Hall sensor with output driver designed for electronic commutation of brushless DC motor applications. The device includes an on-chip Hall sensor for magnetic sensing, an amplifier that amplifies the Hall voltage, a Schmitt trigger to provide switching hysteresis for noise rejection, a temperature compensation circuit to compensate the temperature drift of Hall sensitivity and two complementary open-collector drivers for sinking large load current. It also includes an internal band-gap regulator which is used to provide bias voltage for internal circuits.

Placing the device in a variable magnetic field, if the magnetic flux density is larger than threshold  $B_{OP}$  the pin DO will be turned low (on) and pin DOB will be turned high (off). This output state is held until the magnetic flux density reverses and falls below  $B_{RP}$ , then causes DO to be turned high (off) and DOB turned low (on).

YH279 is available in TO-92S(SIP-3L) package.

### ◆ Typical Applications

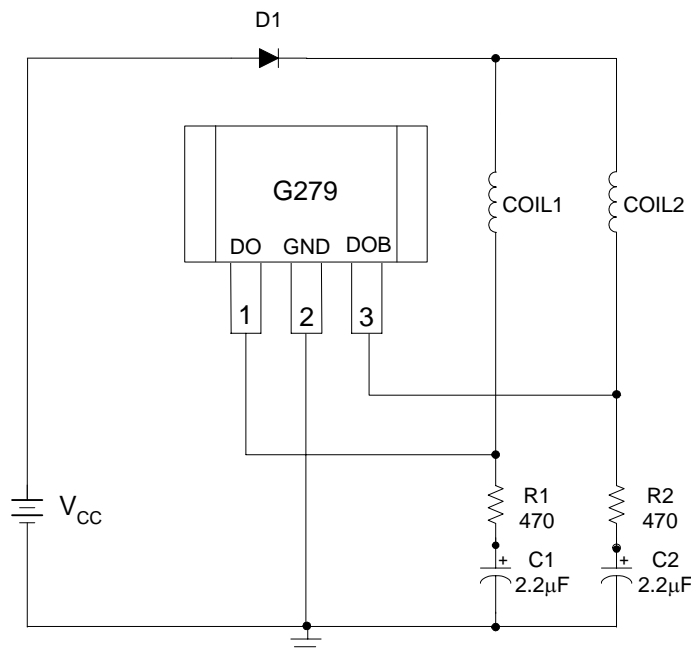


Figure 1. Typical Application Circuit

### ◆ Features

- On-Chip Hall Sensor
- 4.0V to 18V Supply Voltage
- 250mA (avg) Output Sink Current
- Build in Over Zener Diodes Protect Outputs
- -20°C to 85°C Operating Temperature
- Low Profile TO-92S (SIP-3L) Package

### ◆ Applications

- Dual-Coil Brushless DC Motor
- Dual-Coil Brushless DC Fan
- Revolution Counting
- Speed Measurement

## ◆ Pin Configuration

TO-92S(SIP-3L)

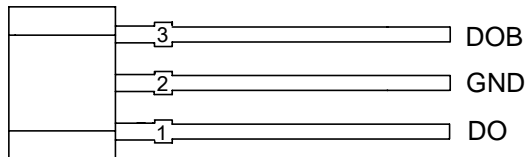


Figure 2. Pin Configuration of YH279 (Front View)

## ◆ Pin Description

Pin Number	Pin Name	Function
1	DO	Coil Driver Output 1, It is Low state during the N magnetic field/Power Input
2	GND	IC Ground
3	DOB	Coil Driver Output 2, It is Low state during the N magnetic field/Power Input

## ◆ Functional Block Diagram

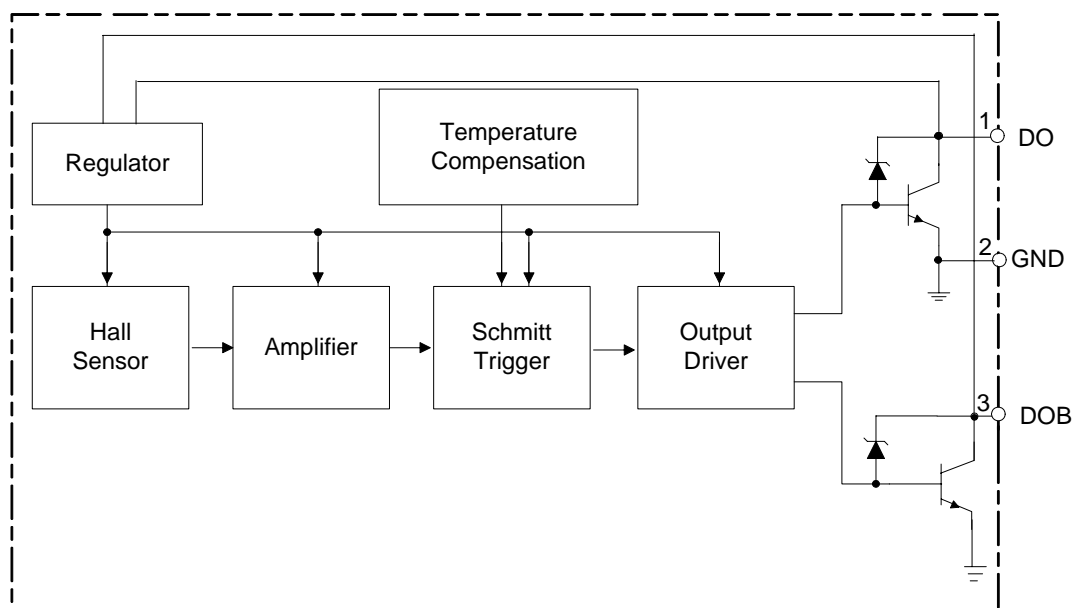


Figure 3. Functional Block Diagram of YH279



## ◆ Absolute Maximum Ratings (Note1)

( $T_A=25^{\circ}\text{C}$ )

Parameter		Symbol	Value	Unit
DO/DOB Pin Voltage		$V_{DO}$ $V_{DOB}$	30	V
Magnetic Flux Density		B	Unlimited	Gauss
Output Current	Continuous	$I_O$	250	mA
	Hold		300	mA
	Peak (Start up)		400	mA
Power Dissipation		$P_D$	550	mW
Thermal Resistance	Die to Atmosphere	$\theta_{JA}$	200	$^{\circ}\text{C}/\text{W}$
	Die to Package Case	$\theta_{JC}$	49	$^{\circ}\text{C}/\text{W}$
Storage Temperature		$T_{STG}$	-50 to 150	$^{\circ}\text{C}$

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. "Absolute Maximum Ratings" for extended period may affect device reliability.

## ◆ Recommended Operating Conditions

( $T_A=25^{\circ}\text{C}$ )

Parameter	Symbol	Min	Max	Unit
Supply Voltage	$V_{CC}$	4.0	18	V
Ambient Temperature	$T_A$	-20	85	$^{\circ}\text{C}$

## ◆ Electrical Characteristics (T<sub>A</sub>=25°C, V<sub>CC</sub>=14V, unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output Saturation Voltage	V <sub>SAT</sub>	B>150Gauss, V <sub>CC</sub> =4.0V, V <sub>DOB</sub> =V <sub>CC</sub> , I <sub>DO</sub> =100mA (or B<-150Gauss, V <sub>CC</sub> =4.0V, V <sub>DO</sub> =V <sub>CC</sub> , I <sub>DOB</sub> =100mA)		0.18	0.3	V
		B>150Gauss, V <sub>DOB</sub> =V <sub>CC</sub> , I <sub>DO</sub> =250mA (or B<-150Gauss, V <sub>DO</sub> =V <sub>CC</sub> , I <sub>DOB</sub> =250mA)		0.3	0.6	V
Supply Current	I <sub>CC</sub>	B>150Gauss, V <sub>DOB</sub> =V <sub>CC</sub> , (or B<-150Gauss, V <sub>DO</sub> =V <sub>CC</sub> )		11	16	mA
Output Rise Time	t <sub>r</sub>	R <sub>L</sub> =1kΩ, C <sub>L</sub> =10pF		3.0	10	μs
Output Fall Time	t <sub>f</sub>	R <sub>L</sub> =1kΩ, C <sub>L</sub> =10pF		0.3	1.5	μs
Switch Time Differential	Δt	R <sub>L</sub> =1kΩ, C <sub>L</sub> =10pF		3.0	10	μs
Output Zener Breakdown Voltage	V <sub>Z</sub>			55		V

service voltage :3.5V

load current :70mA

## ◆ Magnetic Characteristics (T<sub>A</sub>=25°C)

Parameter	Symbol	Grade	Min	Typ	Max	Unit
Operating Point	B <sub>OP</sub>	A	10		50	Gauss
		B	5		70	Gauss
		C			100	Gauss
Releasing Point	B <sub>RP</sub>	A	-50		-10	Gauss
		B	-70		-5	Gauss
		C	-100			Gauss
	B <sub>HYS</sub>			65		Gauss

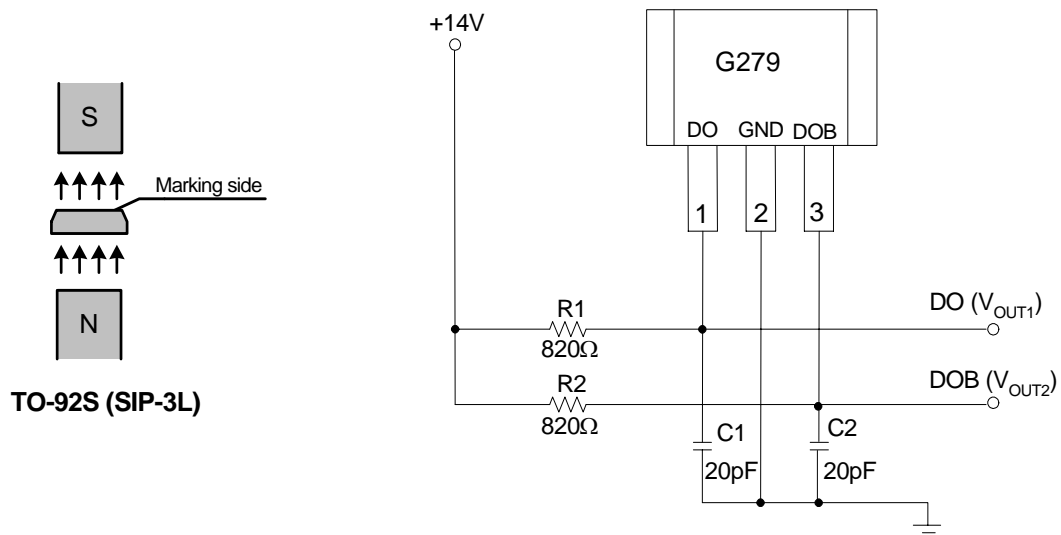


Figure 4. Basic Test Circuit

## ◆ Magnetic Characteristics (Continued)

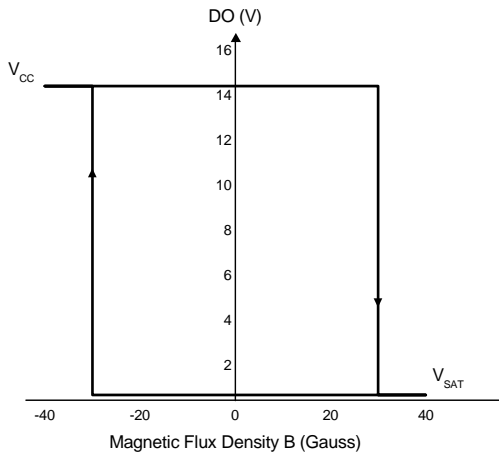


Figure 5.  $V_{DO}$  vs. Magnetic Flux Density

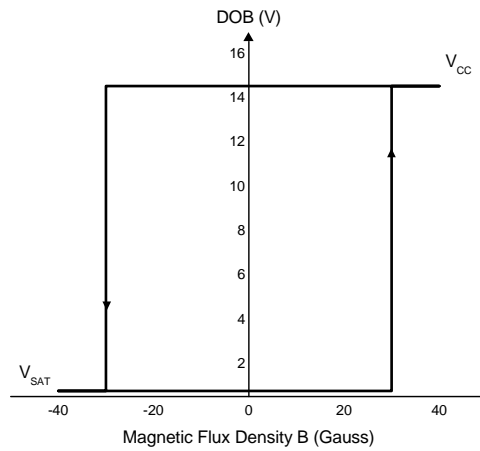
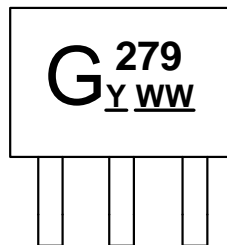


Figure 6.  $V_{DOB}$  vs. Magnetic Flux Density

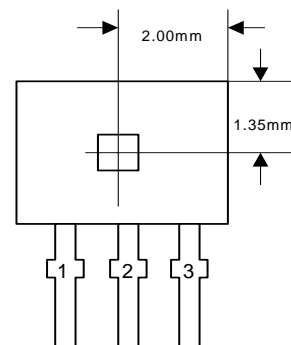
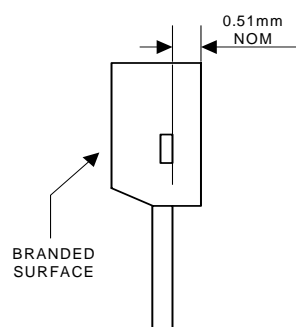
## ◆ Marking Information

( Top View )



Y : Year : 0~9, "2"=2012  
WW : Nth Weeks (01~52)

## ◆ Package Sensor Location (Unit:mm)



◆ **Package Information** (Unit:mm)

